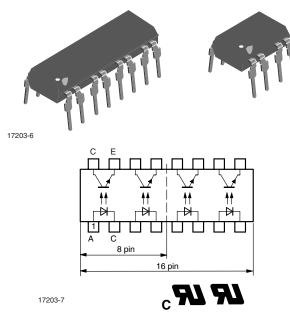


Vishay Semiconductors

Optocoupler, Phototransistor Output



DESCRIPTION

In the K827PH, K847PH parts each channel consist of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 8 pin (dual); 16 pin (quad) plastic dual inline package.

| ORDER INFORMATION | | | | | |
|-------------------|---------------------------|--|--|--|--|
| PART | REMARKS | | | | |
| K827PH | CTR 50 % to 600 %, DIP-8 | | | | |
| K847PH | CTR 50 % to 600 %, DIP-16 | | | | |

Note

K827PH and K847PH are marked as K827P and K847P respectively.

| ABSOLUTE MAXIMUM RATINGS ⁽¹⁾ ($T_{amb} = 25 \degree C$, unless otherwise specified) | | | | | | | |
|---|--------------------------------------|-------------------|-------|------|--|--|--|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT | | | |
| INPUT | | | | | | | |
| Reverse voltage | | V _R | 6 | V | | | |
| Forward current | | I _F | 60 | mA | | | |
| Forward surge current | t _P ≤ 10 µs | I _{FSM} | 1.5 | A | | | |
| Power dissipation | | P _{diss} | 100 | mW | | | |
| Junction temperature | | Tj | 125 | °C | | | |
| OUTPUT | | | | | | | |
| Collector emitter voltage | | V _{CEO} | 70 | V | | | |
| Emitter collector voltage | | V _{ECO} | 7 | V | | | |
| Collector current | | Ι _C | 50 | mA | | | |
| Collector peak current | $t_p/T = 0.5, t_p \le 10 \text{ ms}$ | I _{CM} | 100 | mA | | | |
| Power dissipation | | P _{diss} | 150 | mW | | | |
| Junction temperature | | Tj | 125 | °C | | | |

FEATURES

- DC isolation test voltage 5000 V_{RMS}
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

APPLICATIONS

- Programmable logic controllers
- Modems
- Answering machines
- General applications

AGENCY APPROVALS

- UL1577, file no. E57244 system code H, double protection
- cUL tested to CSA 22.2 bulletin 5A, UL1577, file no. E52744





COMPLIANT



K827PH, K847PH



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| ABSOLUTE MAXIMUM RATINGS ⁽¹⁾ ($T_{amb} = 25 \degree C$, unless otherwise specified) | | | | | | | |
|---|-------------------------------|------------------|---------------|------------------|--|--|--|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT | | | |
| COUPLER | | | | | | | |
| AC isolation test voltage (RMS) | t = 1 min | V _{ISO} | 5000 | V _{RMS} | | | |
| Total power dissipation | | P _{tot} | 250 | mW | | | |
| Operating ambient temperature range | | T _{amb} | - 40 to + 100 | °C | | | |
| Storage temperature range | | T _{stg} | - 55 to + 125 | °C | | | |
| Soldering temperature ⁽²⁾ | 2 mm from case, t \leq 10 s | T _{sld} | 260 | °C | | | |

Notes

(1) Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

⁽²⁾ Refer to wave profile for soldering conditions for through hole devices.

| ELECTRICAL CHARACTERISTICS ⁽¹⁾ ($T_{amb} = 25 \text{ °C}$, unless otherwise specified) | | | | | | | | |
|--|--|--------------------|------|------|------|------|--|--|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT | | |
| INPUT | | | | | | | | |
| Forward voltage | I _F = 50 mA | V _F | | 1.25 | 1.6 | V | | |
| Junction capacitance | V _R = 0 V, f = 1 MHz | Cj | | 50 | | pF | | |
| OUTPUT | | | | | | | | |
| Collector emitter voltage | I _C = 100 μA | V _{CEO} | 70 | | | V | | |
| Emitter collector voltage | I _E = 100 μA | V _{ECO} | 7 | | | V | | |
| Collector dark current | $V_{CE} = 20 \text{ V}, I_F = 0, E = 0$ | I _{CEO} | | | 100 | nA | | |
| COUPLER | | | | | | | | |
| Collector emitter saturation voltage | $I_{\rm F} = 10$ mA, $I_{\rm C} = 1$ mA | V _{CEsat} | | | 0.3 | V | | |
| Cut-off frequency | $I_{F} = 10 \text{ mA}, V_{CE} = 5 \text{ V}, \\ R_{L} = 100 \ \Omega$ | f _c | | 100 | | kHz | | |
| Coupling capacitance | f = 1 MHz | C _k | | 0.3 | | pF | | |

Note

⁽¹⁾ Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

| CURRENT TRANSFER RATIO | | | | | | | |
|--------------------------------|---------------------------------------|--------|--------|------|------|------|------|
| PARAMETER | TEST CONDITION | PART | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| I _C /I _F | V_{CE} = 5 V, I _F = 5 mA | K827PH | CTR | 50 | | 600 | % |
| | | K847PH | CTR | 50 | | 600 | % |



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| SWITCHING CHARACTERISTICS | | | | | | | |
|---------------------------|--|------------------|------|------|------|------|--|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT | |
| Delay time | $\label{eq:VS} \begin{array}{l} V_{S} = 5 \; V, \; I_{C} = 2 \; mA, \; R_{L} = 100 \; \Omega \\ (\text{see figure 1}) \end{array}$ | t _d | | 3 | | μs | |
| Rise time | V_S = 5 V, I _C = 2 mA, R _L = 100 Ω (see figure 1) | t _r | | 3 | | μs | |
| Fall time | $\label{eq:VS} \begin{array}{l} V_{S} = 5 \; V, \; I_{C} = 2 \; mA, \; R_{L} = 100 \; \Omega \\ (\text{see figure 1}) \end{array}$ | t _f | | 4.7 | | μs | |
| Storage time | V_S = 5 V, I _C = 2 mA, R _L = 100 Ω (see figure 1) | t _s | | 0.3 | | μs | |
| Turn-on time | V_S = 5 V, I _C = 2 mA, R _L = 100 Ω (see figure 1) | t _{on} | | 6 | | μs | |
| Turn-off time | V_{S} = 5 V, I _C = 2 mA, R _L = 100 Ω (see figure 1) | t _{off} | | 5 | | μs | |
| Turn-on time | V_S = 5 V, I_F = 10 mA, R_L = 1 k Ω (see figure 2) | t _{on} | | 9 | | μs | |
| Turn-off time | V_S = 5 V, I_F = 10 mA, R_L = 1 k Ω (see figure 2) | t _{off} | | 18 | | μs | |

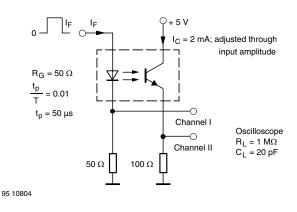


Fig. 1 - Test Circuit, Non-Saturated Operation

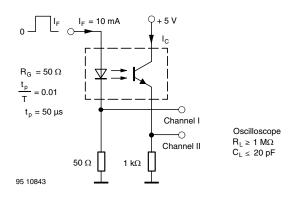


Fig. 2 - Test Circuit, Saturated Operation

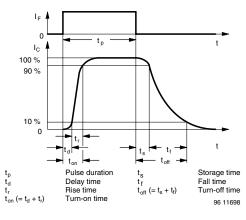


Fig. 3 - Switching Times

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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

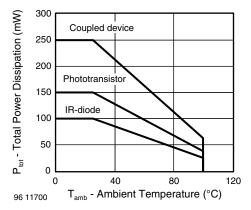


Fig. 4 - Total Power Dissipation vs. Ambient Temperature

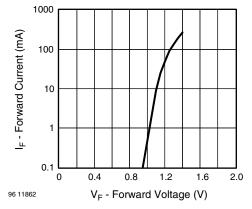


Fig. 5 - Forward Current vs. Forward Voltage

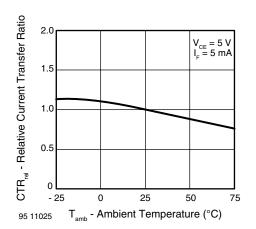


Fig. 6 - Relative Current Transfer Ratio vs. Ambient Temperature

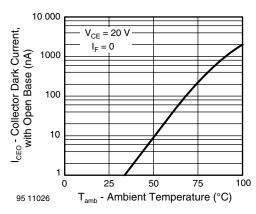
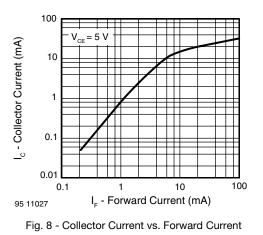
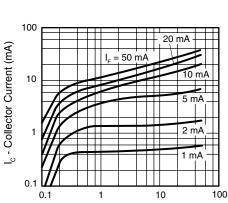


Fig. 7 - Collector Dark Current vs. Ambient Temperature





95 10985 V_{CE} - Collector Emitter Voltage (V)

Fig. 9 - Collector Current vs. Collector Emitter Voltage



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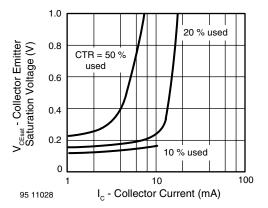


Fig. 10 - Collector Emitter Saturation Voltage vs. Collector Current

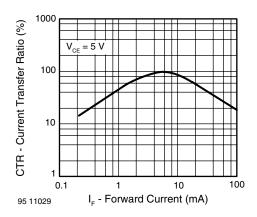


Fig. 11 - Current Transfer Ratio vs. Forward Current

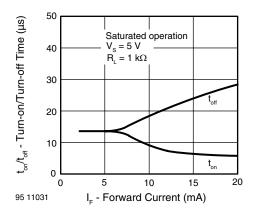


Fig. 12 - Turn-on/Turn-off Time vs. Forward Current

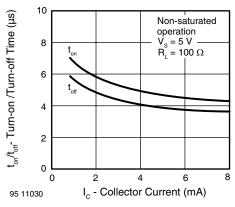
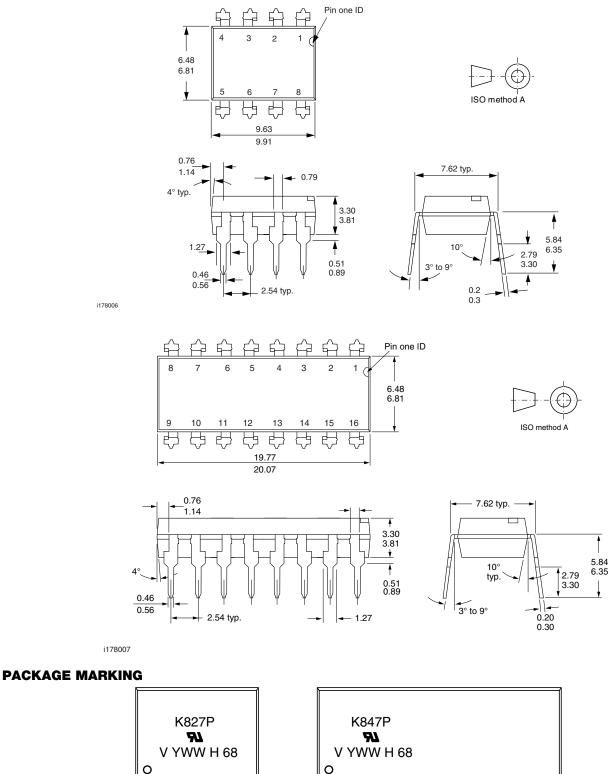


Fig. 13 - Turn-on/off Time vs. Collector Current

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PACKAGE DIMENSIONS in millimeters





Vishay

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